

Abstract

Experimentally, Raman continuum for A_g and B_g geometry exhibits peaks far apart from each other (about 80 to 150 cm^{-1}) in frequency. The former is insensitive to doping over a small range where T_c does not vary much whereas the latter shifts towards higher frequencies. We calculate the electronic Raman scattering intensities using the ‘modified spin bag model’. We show that the calculated results have natural explanation to the observed anomalous peak separation and peculiar doping dependence.

Raman continuum in high- T_c superconductors

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Raman scattering is a powerful technique to probe directly the nature of low energy quasiparticle excitations in superconductors. Raman scattering experiments have been carried out [1–4] to investigate the low energy excitations ($\omega < 1000\text{cm}^{-1}$) of the electronic continuum in the cuprate superconductors. The main puzzling features are,

(1) The Raman continuum which is almost flat for $T > T_c$, becomes depleted below T_c at low frequencies ($\omega < 200\text{ cm}^{-1} < 2\Delta_{sc}$) and a broad peak develops in the range $250 - 600\text{ cm}^{-1}$. The central frequency of this peak depends on the material studied and the scattering geometry (that is the part of the Fermi surface (FS) being explored), but it is developed much above the superconducting

gap threshold. The dependence of the peak position on the scattering geometry shows that the superconducting (SC) gap is highly anisotropic.

(2) There is some residual intensity below $\omega < 2\Delta_{sc}$, showing that scattering with quasiparticles still exists even below the T_c . It is generally believed to be due to possible existence of nodes on the gap function, and hence the availability of low energy quasiparticles even below the T_c .

For superconductors in which the penetration depth of the incident light is much greater than the BCS coherence length, the electronic Raman scattering intensity follows from the $q \approx 0$ limit only, q being the momentum transfer to the quasiparticles. The Raman scattered intensity due to the scattering by the superconducting quasipar-

ties is given by,

$$I(0, \omega) = \frac{1}{\pi^2 \omega} \int_{\omega > 2|\Delta_k|} \frac{|\gamma_k|^2 \Delta_k^2 d^2k}{(\omega^2 - 4\Delta_k^2)^{1/2}} \tanh\left(\frac{\omega}{4T}\right) \quad (1)$$

The integral is over the Fermi surface.

It is observed that, for the A_{1g} mode, the Raman intensity decreases linearly with ω at lower frequencies and extrapolates to zero at $\omega = 0$. This seems to support a d-wave kind of SC-gap which has nodes on the Fermi surface, and the A_{1g} continuum is due to excitations of superconducting pairs across an anisotropic with d-wave type nodes, with $2\Delta_{\max} = 310 \text{ cm}^{-1}$. The surprising thing about the A_{1g} continuum is that the peak position is independent of small doping variation and there is very little variation in intensity also.

But for the B_{1g} mode, the peak frequency differs from the A_{1g} continuum peak by about 200 cm^{-1} .

Also this peak position shifts towards higher frequencies for compounds with lesser concentration of oxygen or rather for lower hole doping.

There are arguments [5], saying that one can obtain different peak positions, once one takes the screening effects into account. On the other hand, it has been argued [5,6] that, screening is effective more in the s-wave scattering channel, and hence a look at the different structure factors for the two phonons tells us that screening should substantially reduce the A_{1g} phonon scattered intensity and the intensity of the B_{1g} mode will not be affected much. In other words the B_{1g} continuum will be stronger than the A_{1g} continuum. This is exactly opposite to what is observed experimentally

[7]. Another important point worth emphasizing is that, since the A_{1g} and B_{1g} modes corresponds to the breathing oxygen atom vibrations and antisymmetric out of plane vibrations of the oxygen cage around the Cu atom respectively, one expects the A_{1g} continuum to be sensitive to the carrier concentrations or the oxygen content, while the B_{1g} continuum should be relatively unaffected. This again is exactly opposite to what is experimentally observed [7]. Screening doesn't seem to be important at all. The alternative hypothesis put forward, is that the B_{1g} peak is not associated with the superconducting gap at all, since the peaking in intensity at higher frequency for this mode is observed even slightly above T_c . Scattering with spin fluctuations is put forward as a pos-

sible explanation for this, since for lower doped materials a spin gap like feature is observed above T_c and the magnitude of which reduces with doping. It is argued that, if the peaking in the B_{1g} mode is due to the superconducting gap then how could the peak position vary by about 20 percent, within a doping variation that changes T_c very little? Here we explore these features theoretically within our model.

Our model is based on the idea of Schrieffer's spin bag model [8] with coupling between the planes explicitly introduced to analyze two layer systems. At half filling due to the square planar nature of the Fermi surface (nesting) and intermediate inplane correlation between the Cu spins leads to SDW insulating phase with a fully gapped FS. With doping,

nesting is lost near the M points and hence the SDW gap vanishes in these directions while surviving in other directions. This effect is enhanced with the introduction of single particle tunneling between the planes. The pairing interaction between the low energy SDW quasiparticles in the gapless regions is mediated by the quanta of fluctuations of the amplitude and phase modes of the SDW gap in the surviving regions [9]. Notable difference with earlier treatments is that the conduction and valence bands touch each other in the regions where the nesting is lost and thereby the SDW gap G is assumed to be zero in these regions while solving the self-consistent SDW gap equation. The coupling between the SDW quasiparticles and the fluctuations of the amplitude

and phase (i.e, collective) modes of the SDW state, will give rise to new kind of electron-amplitudon (phason) interaction. Such interaction in a second order perturbation theory gives rise to an effective pairing interaction is the essence of the modified spin bag mechanism [9]. The superconducting gap equation from our model is given below,

$$\begin{aligned} \Delta_{sc}(k) = & \sum_{k'} [\lambda_1 + \lambda_2 \frac{(\epsilon_k - \mu)(\epsilon_{k'} - \mu)}{E_k E_{k'}} \\ & - \frac{G(k)G(k')}{E_k E_{k'}}] (\Delta_{sc}(k')/e_{k'}) \\ & \times \tanh(\beta e_{k'}/2) \end{aligned} \quad (2)$$

where,

$\lambda_{1(2)} = \Omega_{AM} U^2 / [(E_k \mp E_{k'})^2 - \Omega_{AM}^2]$, and Ω_{AM} being the maximum frequency of the SDW gap fluctuation (amplitudon) given by, $\Omega_{AM} = 2G_{max}$. Where $e_k = \sqrt{E_k^2 + \Delta_{sc}^2}$ and $E_k = [(\epsilon_k - \mu)^2 + G^2]^{1/2}$ are respectively the SC and SDW quasiparticle energies. It is clear

that the SC-gap will peak up to its maximum for the (k_x, k_y) points where $G(k)$ vanishes and hence the two gaps (SDW and SC) will have complementary nature.

We solved both the SDW and superconducting gap equations numerically for different filling factors. Parameters chosen are, $t = 0.3$ eV, $U = 2.0$ eV, pairing interaction cutoff for the SDW gap equation to be 75 meV. With these values and for chemical potential $\mu = -250$ meV we get an SDW transition temperature T_{sdw} of 100°K , $t_\perp$ is taken to be 0.05 eV. For the superconducting gap equation the pairing cutoff is $-G$ to G (the maximum SDW gap). We choose, $\lambda_1 = 50$ and $\lambda_2 = 40$ meV to get a T_c of 85°K for $\mu = -250$ meV. T_c decreases by 7 degrees when the chemical potential is var-

ied upto -200 meV (that is for a doping concentration of 0.14 to 0.12, measured from half filling). The self consistent gap equation is solved numerically for 3 different doping concentrations. The main feature of the gap is that, it is larger near the M points than near the X points by 3-4 meV. Also the gap near the M points falls slower with temperature than the gaps near the X points. Of course we do not have any gap nodes and the gap values near the X points is still substantial (10-12 meV) for such small doping concentrations. So we do not get any Raman intensity in the low frequency region. We discuss the results of our numerical calculations below.

For the B_{1g} mode, the structure factor γ_k also is maximum wherever the gap is maximum, and most

of the contribution to the scattered intensity in this channel comes from quasiparticles in these regions. On the other hand, for the A_{1g} , the structure factor is large and more or less flat in almost all regions in the Brillouin zone and falls to low values at the places where the gap value is maximum. In other words most of the scattered Raman intensity in this channel are from the region where the gap value is small.

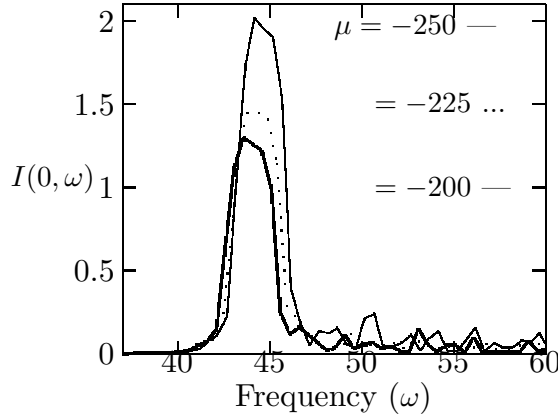


Fig.1 Electronic Raman continuum intensity versus frequency (in meV) in the A_{1g} geometry at $T = 20^\circ\text{K}$, for different dopings.

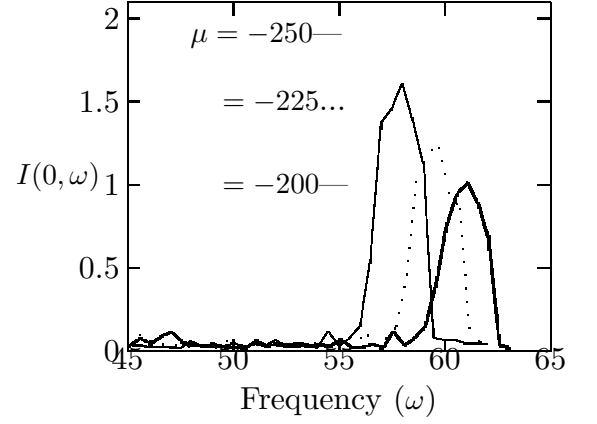


Fig.2 Electronic Raman continuum intensity versus frequency (in meV) in the B_{1g} geometry at $T = 20^\circ\text{K}$, for different dopings.

With larger doping the fermi surface moves away from the region where the gap is maximum. So for the B_{1g} geometry the peak in the Raman spectra will shift towards lower frequency (cf Fig.2). On the other hand for the A_{1g} mode most of the contributions are from the regions away from corners where the SC gap is large, because the structure factor is very small there. Therefore, for the A_{1g} mode, quasiparticles from

almost all regions contribute equally to the scattered intensity and hence for small doping variations or for small shrinkage of the Fermi surface, there is no noticeable effects at all (Fig.1).

REFERENCES

- [1] X. K. Chen, E. Altendorf, J. C. Arwin, R. Liang and H. Hardy, Phys. Rev. **B 48** (1993), 10530 ; Phys. Rev. **B 47** (1993) 8140.
- [2] S. Sugai, Y. Enomoto and T. Muramaki, Solid. State. Commn **75** (1990), 975.
- [3] S. L. Cooper, F. Slakey, M. V. Klein, J. P. Rice and D. M. Ginsberg, Phys. Rev. **B 37** (1988), 5920 ; Phys. Rev. **B 38** (1988), 11934.
- [4] T. Staufer, R. Newetchek, R. Hackl, P. Muller and H. Veith, Phys. Rev. Lett. **68** (1992), 1069.
- [5] T. Devereaux, D. Einzel, B. Stadlober, R. Hackl, D. H. Leach and J. J. Neumeier, Phys. Rev. Lett. **72** (1994), 396.
- [6] M. V. Klein and S. B. Dierker, Phys. Rev **B 29** (1983), 4976.
- [7] X. K. Chen, J. C. Irwin, R. Liang and W. N. Hardy, Physica **C 227** (1994), 113.
- [8] J. R. Schrieffer, X. G. Wen and S. C. Zhang, Phys. Rev B **39** (1989), 11663 ; A. P. Kampf and J. R. Schrieffer, Phys. Rev. **B 41** (1990), 6399.
- [9] H. N. Ghosh and S. N. Behera, Ind. J. Phys. **A 69**, (1995) 14 ; S. N. Behera and H. N.

Ghosh, Z. Phys. **B 95** (1994), 275; Haranath Ghosh and M. Sardar, Physica **C 246** (1995),335.

- [10] S. Chakraborty, A. Sudbo, P. W. Anderson and S. Strong, Science **261** (1993), 337.

FIGURE CAPTIONS

Fig.1 Electronic Raman continuum intensity versus frequency (in meV) in the A_{1g} geometry at $T= 20^\circ\text{K}$, for different dopings.

Fig.2 Electronic Raman continuum intensity versus frequency (in meV) in the B_{1g} geometry at $T = 20^\circ\text{K}$, for different dopings.